TOSHIBA CCD Linear Image Sensor CCD (charge coupled device)

# TCD2561D

The TCD2561D is a high sensitive and low dark current 5340 elements  $\times 4$  line CCD color image sensor which includes CCD drive circuit, clamp circuit.

The sensor is designed for scanner. The device contains a row of 5340 elements  $\times$  4 line photodiodes which provide a 24 lines/mm across a A4 size paper. The device is operated by 5 V pulse and 12 V power supply.

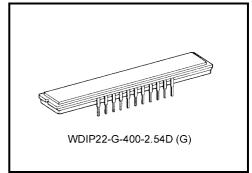
### Features

- Number of image sensing elements: 5340 elements × 4 line
- Image sensing element size:  $7~\mu\text{m} \times 7~\mu\text{m}$  on  $7~\mu\text{m}$  centers
- Photo sensing region: High sensitive PN photodiode
- Distanced between photodiode array: Color (28 μm, 4 lines), B/W-color (56 μm, 8 lines)
- Clock: 2 phase (5 V)
- Power supply: 12 V power supply voltage
- Internal circuit: Clamp circuit
- Package: 22 Pin CERDIP package
- Color filter: Red, green, blue

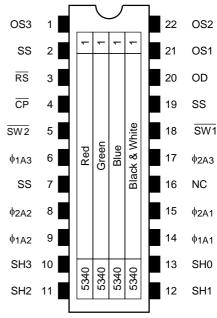
### Maximum Ratings (Note1)

Characteristic	Symbol	Rating	Unit	1
Clock pulse voltage	V <sub>¢</sub>		V	1
Shift pulse voltage	V <sub>SH</sub>	-	V	1
Reset pulse voltage	VRS	-0.3~8.0	V	1
Clamp pulse voltage	VCP		V	1
Changeover switch voltage	VSW		V	
Power supply voltage	V <sub>OD</sub>	-0.3~15	V	
Operating temperature	T <sub>opr</sub>	0~60	°C	
Storage temperature	T <sub>stg</sub>	-25~85	°C	

Note 1: All voltage are with respect to SS terminals (ground).

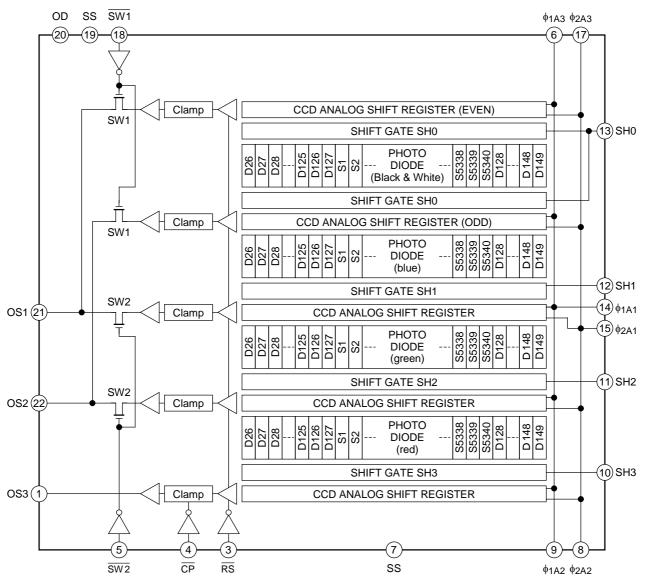


Weight: 5.2 g (typ.)



**Pin Connections (top view)** 

### **Circuit Diagram**



### **Pin Names**

OS3	Signal Output 3 (red)	OS2	Signal Output 2 (green)
SS	Ground	OS1	Signal Output 1 (blue)
RS	Reset Gate	OD	Power
CP	Clamp Gate	SS	Ground
SW2	Changeover Switch 2 (color and B/W)	SW1	Changeover Switch 1 (color and B/W)
ф1АЗ	Clock 3 (phase 1)	\$2A3	Clock 3 (phase 2)
SS	Ground	NC	Non Connection
ф2А2	Clock 2 (phase 2)	¢2A1	Clock 1 (phase 2)
ф1А2	Clock 2 (phase 1)	\$1A1	Clock 1 (phase 1)
SH3	Shift Gate 3	SH0	Shift Gate 0
SH2	Shift Gate 2	SH1	Shift Gate 1

### **Optical/Electrical Characteristics**

(Ta = 25°C, V<sub>OD</sub> = 12 V, V<sub> $\phi$ </sub> = V<sub>RS</sub> = V<sub>SH</sub> = V<sub>CP</sub> = 5 V (pulse), f<sub> $\phi$ </sub> = 1.0 MHz, f<sub>RS</sub> = 1.0 MHz, LOAD RESISTANCE = 100 k $\Omega$ , t<sub>INT</sub> (INTEGRATION TIME) = 10 ms, LIGHT SOURCE = A LIGHT SOURCE + CM500S FILTER (t = 1.0 mm))

Characteristics	Symbol	Min	Тур.	Max	Unit	Note
	R <sub>B/W</sub>	16.8	21.0	25.2		
Sensitivity	R <sub>R</sub>	6.3	9.0	11.7	V/(lx·s)	(Note 2)
Sensitivity	R <sub>G</sub>	7.3	10.5	13.7	v/(ix*5)	(NOLE 2)
	R <sub>B</sub>	3.8	5.5	7.2		
Photo response non uniformity	PRNU (1)	_	10	20	%	(Note 3)
Photo response non uniformity	PRNU (3)	_	3	12	mV	(Note 4)
Image lag	IL	_	1	_	%	(Note 5)
Saturation output voltage (B/W)	V <sub>SAT (B/W)</sub>	1.5	2.0	_	V	(Note 6)
Saturation output voltage (color)	V <sub>SAT</sub> (color)	3.2	3.5		V	(Note 6)
Saturation exposure	SE		0.1		lx∙s	(Note 7)
Dark signal voltage	V <sub>DRK</sub>	_	0.4	2.0	mV	(Note 8)
Dark signal non uniformity	DSNU	_	7	12	mV	(Note 8)
DC power dissipation	PD		480	690	mW	
Total transfer efficiency	TTE	92			%	
Output impedance	ZO	_	0.3	1.0	kΩ	
DC signal output voltage	V <sub>OS</sub>	5.0	6.0	7.0	V	(Note 9)
Random noise	N <sub>Dσ</sub>	_	1.0	_	mV	(Note 10)
Reset noise	V <sub>RSN</sub>	_	0.5	1.0	V	(Note 9)

Note 2: Sensitivity is defined for each color of signal outputs average when the photosensitive surface is applied with the light of uniform illumination and uniform color temperature.

Note 3: PRNU (1) is defined for each color on a single chip by the expressions below when the photosensitive surface is applied with the light of uniform illumination and uniform color temperature.

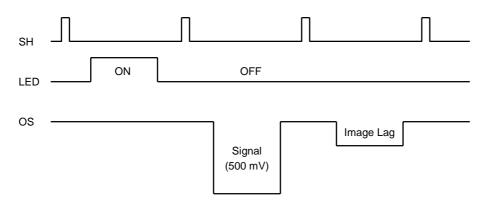
PRNU (1) = 
$$\frac{\Delta X}{\overline{X}} \times 100$$
 (%)

When  $\overline{X}$  is average of total signal output and  $\Delta X$  is the maximum deviation from  $\overline{X}$ . The amount of incident light is shown below.

Red = 
$$\frac{1}{2}$$
 SE, Green =  $\frac{1}{2}$  SE, Blue =  $\frac{1}{4}$  SE

Note 4: PRNU (3) is defined as maximum voltage with next pixel, where measured 5% of SE (typ.)

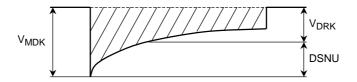
Note 5: Image Lag is defined as follows.



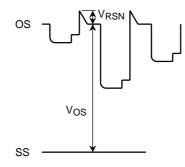
Note 6: V<sub>SAT</sub> is defined as minimum saturation output of all effective pixels.

Note 7: Definition of SE: SE =  $\frac{V_{SAT}}{R_{B/W}}$  (Ix · s)

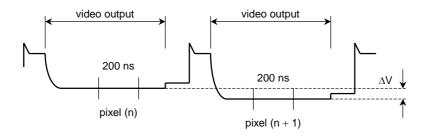
Note 8: V<sub>DRK</sub> is defined as average dark signal voltage of all effective pixels. DSNU is defined as different voltage between V<sub>DRK</sub> and V<sub>MDK</sub> when V<sub>MDK</sub> is maximum dark signal voltage.



Note 9: DC signal Output Voltage and Reset Noise is defined as follows, but Reset Noise is a fixed pattern noise.



Note 10: Random noise is defined as the standard deviation (sigma) of the output level difference between two adjacent effective pixels under no illumination (i.e. dark conditions) calculated by the following procedure.



Output waveform (effective pixels under dark condition)

- (1) Two adjacent pixels (pixel n and n + 1) in one reading are fixed as measurement points.
- (2) Each of the output level at video output periods averaged over 200 ns period to get V (n) and V (n + 1).
- (3) V (n + 1) is subtracted from V (n) to get  $\Delta V$ .  $\Delta V = V$  (n) - V (n + 1)
- (4) The standard deviation of  $\Delta V$  is calculated after procedure (2) and (3) are repeated 30 times (30 readings)

$$\frac{1}{30}\sum_{i=1}^{30} |\Delta Vi| \qquad \qquad \sigma = \sqrt{\frac{1}{30}\sum_{i=1}^{30} (|\Delta V_i| - \overline{\Delta V})^2}$$

- (5) Procedure (2), (3) and (4) are repeated 10 times to get sigma value.
- (6) 10 sigma values are averaged.

 $\overline{\Delta V} = -$ 

$$\overline{\sigma} = \frac{1}{10} \sum_{j=1}^{10} \sigma_j$$

(7)  $\overline{\sigma}$  value calculated using the above procedure is observed  $\sqrt{2}$  times larger than that measured relative to the ground level. So we specify random noise as follows.

$$N_{D\sigma} = \frac{1}{\sqrt{2}}\overline{\sigma}$$

# <u>TOSHIBA</u>

### **Operating Condition**

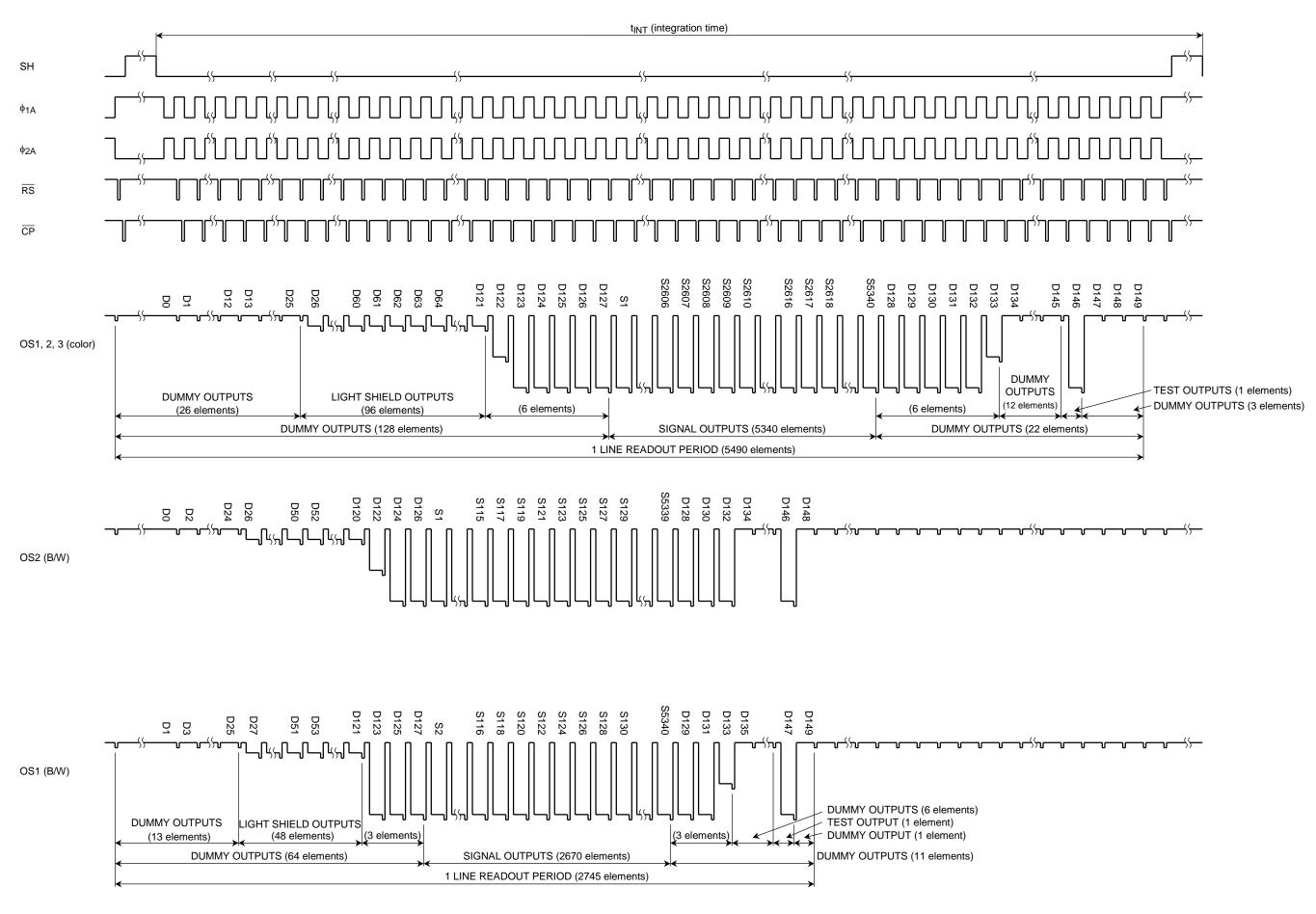
Characteristics		Symbol	Min	Тур.	Max	Unit	Note
Clock pulse voltage	"H" Level	$V_{\phi A}$	4.5	5.0	5.5	V	
Clock pulse voltage	"L" Level	νφA	0	—	0.5		
Shift pulse voltage	"H" Level	V <sub>SH</sub>	4.5	5.0	5.5	- V	
Shin pulse voltage	"L" Level	V SH	0	—	0.5		
	"H" Level		4.5	5.0	5.5	V	
Reset pulse voltage	"L" Level	VRS	0	_	0.5		
	"H" Level		4.5	5.0	5.5	v	
Clamp pulse voltage	"L" Level	VCP	0		0.5	v	
Switch pulse veltage	"H" Level		4.5	5.0	5.5	v	
Switch pulse voltage	"L" Level	VSW	0	—	0.5	v	
Power supply voltage		V <sub>OD</sub>	11.4	12.0	13.0	V	

### Clock Characteristics (Ta = 25°C)

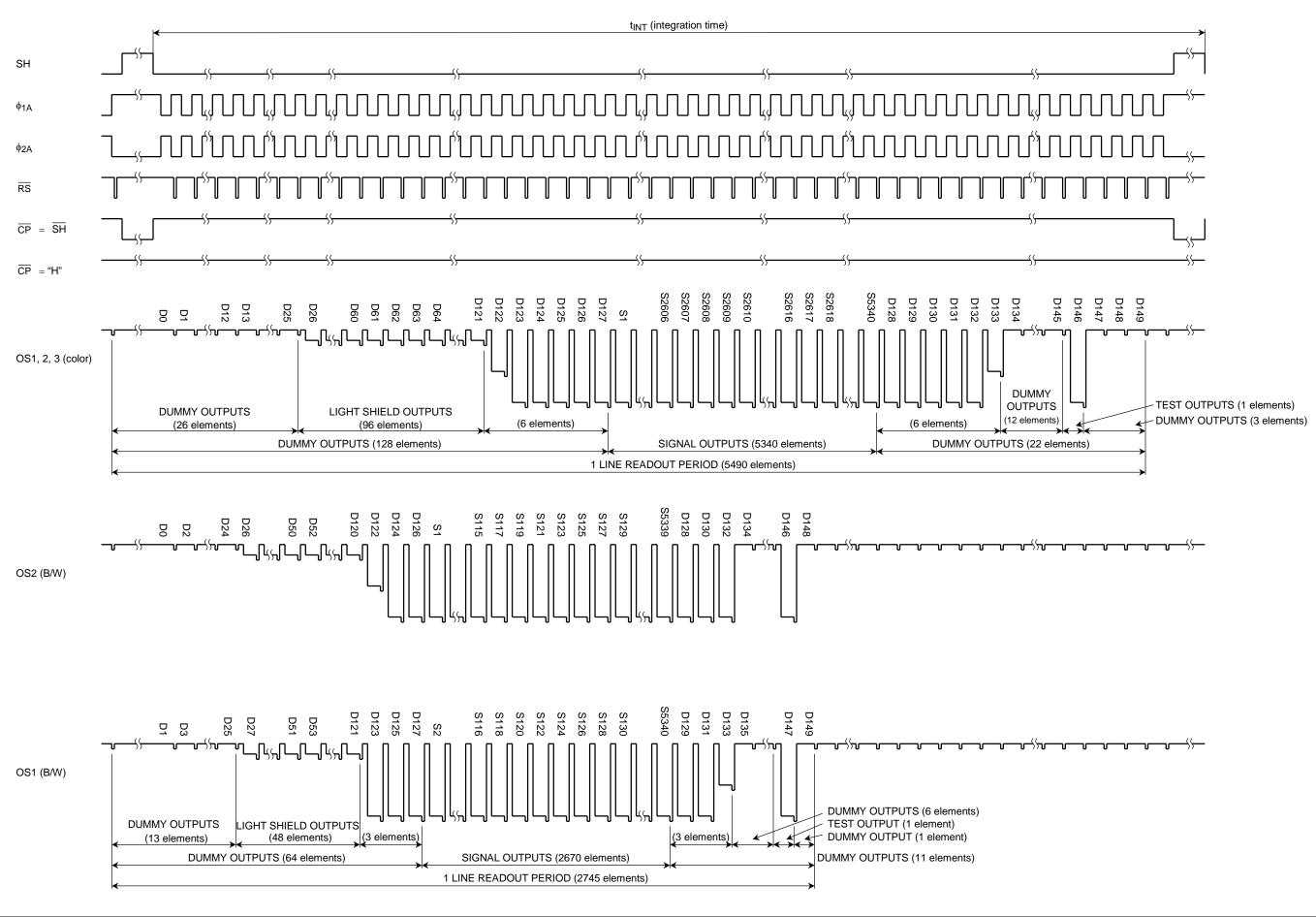
Characteristics	Symbol	Min	Тур.	Max	Unit
Clock pulse frequency	f <sub>¢</sub>	0.3	1.0	10	MHz
Reset pulse frequency	fRS	0.3	1.0	10	MHz
Clamp pulse frequency	fCP	0.3	1.0	10	MHz
Clock1 capacitance (Note 11)	C <sub>¢1</sub>	_	160	240	рF
Clock2 capacitance (Note 11)	C <sub>¢2</sub>	_	130	195	рF
Shift gate capacitance	C <sub>SH</sub>	_	30	60	рF
Reset gate capacitance	CRS	_	10	40	рF
Clamp gate capacitance	CCP	_	10	40	pF
Switch gate capacitance	Csw	_	10	40	рF

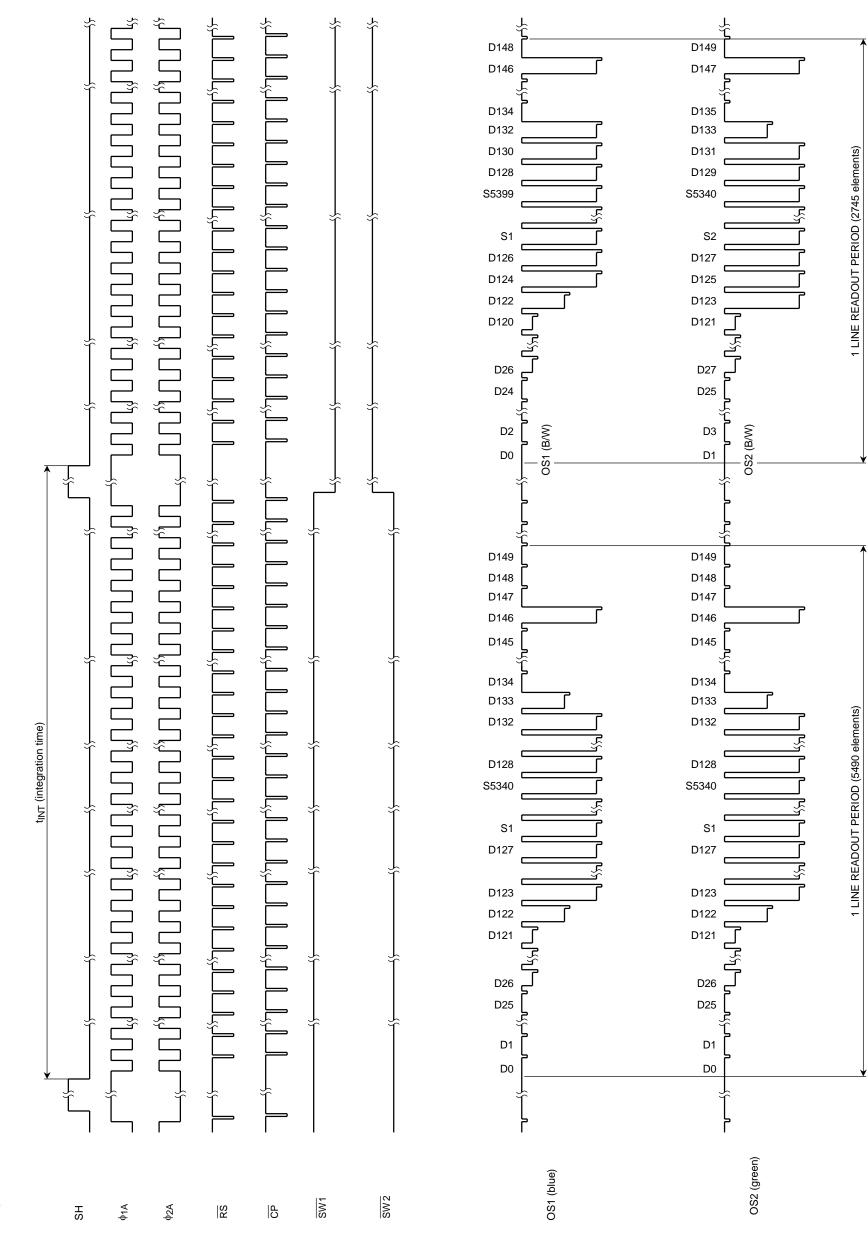
Note 11: V<sub>OD</sub> = 12 V

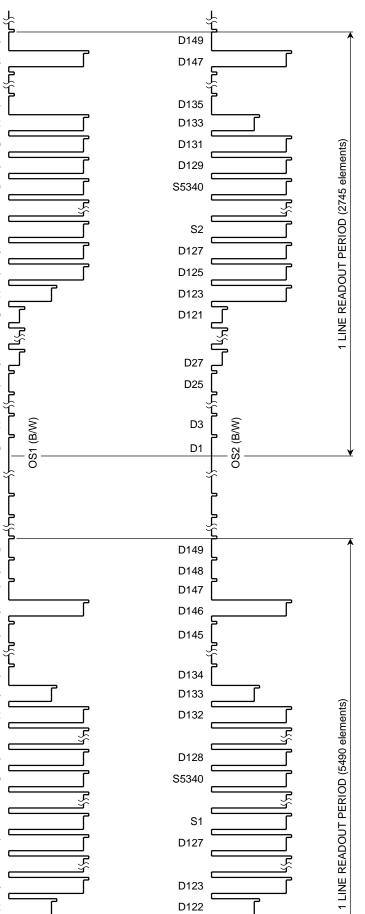
Timing Chart 1: Bit Clamp Mode (color or B/W mode)



Timing Chart 2: Line Clamp Mode (color or B/W mode)



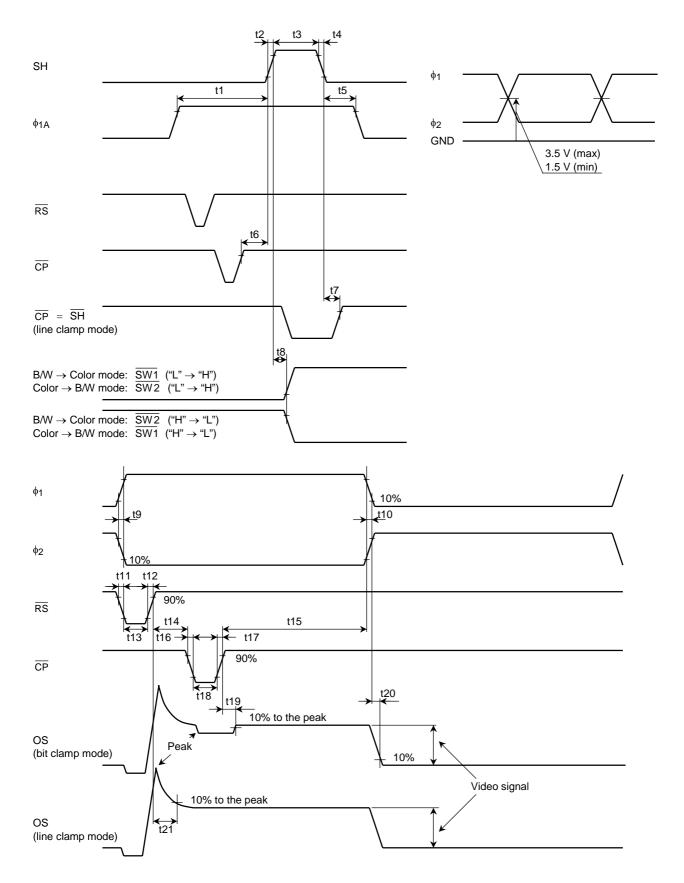






# Timing Chart 3 (color $\rightarrow$ B/W mode)

### **Timing Requirements**



### **Timing Requirements (cont.)**

Characteristics	Symbol	Min	Typ. (Note 12)	Max	Unit
Pulse timing of SH and	t1	120	1000	—	ns
	t5	800	1000		115
SH pulse rise time, fall time	t2, t4	0	50	_	ns
SH pulse width	t3	3000	5000		ns
Pulse timing of SH and CP	t6	200	500		ns
Pulse timing of SH and CP (line clamp mode)	t7	10	100		ns
Pulse timing of SH and SW	t8	100	500	t3 – 100	ns
$\phi$ 1, $\phi$ 2 pulse rise time, fall time	t9, t10	0	50		ns
RS pulse rise time, fall time	t11, t12	0	20		ns
RS pulse width	t13	10 (20)	80		ns
Pulse timing of RS and CP	t14	0	40		ns
Pulse timing of $\phi_{1A}$ , $\phi_{2A}$ and $\overline{CP}$	t15	0	20		ns
CP pulse rise time, fall time	t16, t17	0	20		ns
CP pulse width (Note 13)	t18	30 (3000)	80 (5000)		ns
Reference level settle time (bit clamp mode)	t19	_	20	40 (Note 16)	ns
Video data delay time (Note 14)	t20	_	20	40 (Note 15)	ns
Reference level settle time (line clamp mode)	t21	_	30	50 (Note 16)	ns

Note 12: Typ. is the case of  $f_{\overline{RS}} = 1.0$  MHz.

Note 13: Line clamp Mode inside ().

Note 14: Load Resistance is 100 k $\Omega$ .

Note 15: Typical settle time to about 1% of final value.

Note 16: Typical settle time to about 1% of the peak.

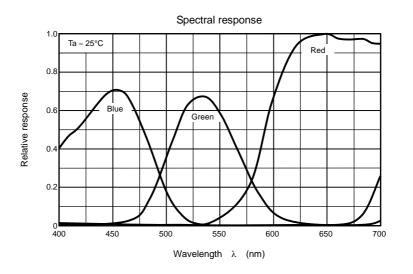
### **Clamp Mode**

Clamp Means	CP Input Pulse
Bit Clamp	CP Pulse
Line Clamp	"H" or SH

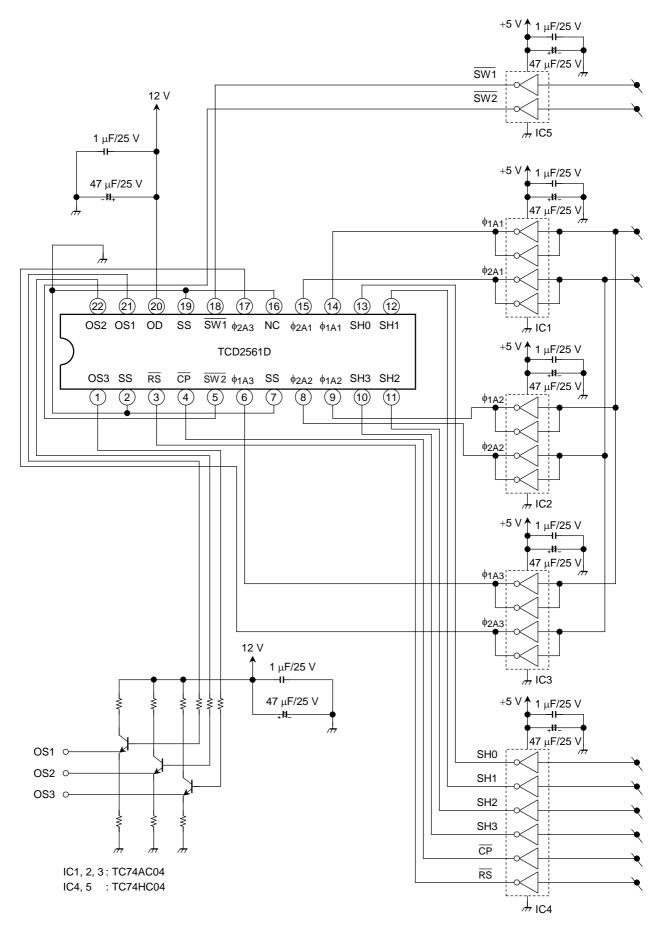
### **Changeover Switch Mode**

Output Type	SW1 Input Pulse	SW2 Input Pulse
Color	"H"	"L"
B/W	"L"	"H"

### **Typical Spectral Response**



### **Typical Drive Circuit**



### Caution

### 1. Window Glass

The dust and stain on the glass window of the package degrade optical performance of CCD sensor. Keep the glass window clean by saturating a cotton swab in alcohol and lightly wiping the surface, and allow the glass to dry, by blowing with filtered dry N2. Care should be taken to avoid mechanical or thermal shock because the glass window is easily to damage.

### 2. Electrostatic Breakdown

Store in shorting clip or in conductive foam to avoid electrostatic breakdown.

CCD Image Sensor is protected against static electricity, but interior puncture mode device due to static electricity is sometimes detected. In handing the device, it is necessary to execute the following static electricity preventive measures, in order to prevent the trouble rate increase of the manufacturing system due to static electricity.

- a. Prevent the generation of static electricity due to friction by making the work with bare hands or by putting on cotton gloves and non-charging working clothes.
- b. Discharge the static electricity by providing earth plate or earth wire on the floor, door or stand of the work room.
- c. Ground the tools such as soldering iron, radio cutting pliers of or pincer.

It is not necessarily required to execute all precaution items for static electricity. It is all right to mitigate the precautions by confirming that the trouble rate within the prescribed range.

### 3. Incident Light

 $\rm CCD$  sensor is sensitive to infrared light. Note that infrared light component degrades resolution and PRNU of CCD sensor.

### 4. Lead Frame Forming

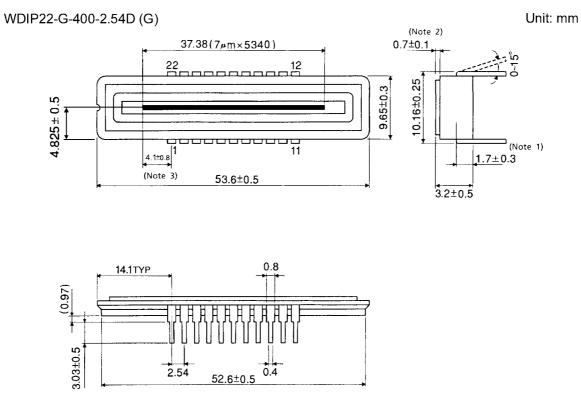
Since this package is not strong against mechanical stress, you should not reform the lead frame. We recommend to use a IC-inserter when you assemble to PCB.

### 5. Soldering

Soldering by the solder flow method cannot be guaranteed because this method may have deleterious effects on prevention of window glass soiling and heat resistance.

Using a soldering iron, complete soldering within ten seconds for lead temperatures of up to 260°C, or within three seconds for lead temperatures of up to 350°C.

### Package Dimensions



(Note 1) : TOP OF CHIP TO BOTTOM OF PACKAGE.

(Note 2) : GLASS THICKNESS (n = 1.5)

(Note 3) : No.1 SENSOR ELEMENT (S1) TO EDGE OF No.1 PIN.

Weight: 5.2 g (typ.)

### **RESTRICTIONS ON PRODUCT USE**

Handbook" etc..

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